NSN 5961-01-427-9147

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View Online at https://aerobasegroup.com/nsn/5961-01-427-9147 **Inclosure Material:** Metal **Overall Length:** 1.330 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.667 inches and 0.687 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 collector to base voltage/static/emitter open and 400.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 20.00 amperes source cutoff current and 2.50 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 82577-928883 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: